Large Exchange Bias after Zero-Field Cooling from an Unmagnetized State

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Exchange bias (EB) is usually observed in systems with an interface between different magnetic phases after field cooling. Here we report an unusual phenomenon in which a large EB can be observed in Ni-Mn-In bulk alloys after zero-field cooling from an unmagnetized state. We propose that this is related to the newly formed interface between different magnetic phases during the initial magnetization process. The magnetic unidirectional anisotropy, which is the origin of the EB effect, can be created isothermally below the blocking temperature.

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When a system consisting of ferromagnetic (FM)-antiferromagnetic (AFM) [1], FM-spin glass (SG) [2], AFM-ferrimagnetic [3], and FM-ferrimagnetic [4] interfaces is cooled with the field through the Néel temperature ($T_N$) of the AFM or glass temperature ($T_{SG}$) of the SG, exchange bias (EB) is induced showing a shift of the hysteresis loop [$M(H)$] along the magnetic field axis. Since its discovery by Meiklejohn and Bean in 1956 [1], EB has been extensively studied during the past 50 years, partly because of its applications in ultrahigh-density magnetic recording, giant magnetoresistance, and spin valve devices [5,6]. The EB effect is attributed to a FM unidirectional anisotropy formed at the interface between different magnetic phases [5]. Generally, the process of field cooling (FC) from higher temperature is used to obtain FM unidirectional anisotropy in different EB systems [1–4]. The FM unidirectional anisotropy can also be realized by depositing the AFM layer onto a saturated FM layer [5], by ion irradiation in an external magnetic field [7], by zero-field cooling (ZFC) with remnant magnetization [8,9]. In a word, the FM unidirectional anisotropy in these EB systems is formed by reconfiguring the FM spins at the interface between different magnetic phases. Here, we named the previous EB generally observed after FC as the conventional EB (CEB). Furthermore, Saha et al. [10] argued that a small spontaneous EB observed after ZFC without remnant magnetization, which has been ignored or attributed to the experimental artifact, can be explained theoretically in an otherwise isotropic EB system. The CEB effect after FC has also been observed in NiMn-based Heusler bulk alloys, such as NiMnSn [11], NiMnSb [12], and NiMnIn [13], coexisting of AFM and FM phases. In this Letter, we report a large EB effect (the maximum EB field is about 1300 Oe at 10 K) after ZFC from an unmagnetized state in Ni-Mn-In bulk alloys. Namely, a large FM unidirectional anisotropy can be produced isothermally, which has never been reported to date and cannot be expected in the CEB systems [14].

The details of sample preparations and measurements for Ni$_{x}$Mn$_{50-x}$In$_{x}$ (NiMnIn$_x$, $x = 11, 12, 13, 14,$ and 15) alloys are illustrated in the supplementary information [14]. Two measurement processes can be used to obtain a closed $M(H)$ loop after ZFC [only consider $(+H) = [-H]$]: (1) $P$ type, $0 \rightarrow (+H) \rightarrow 0 \rightarrow (-H) \rightarrow 0 \rightarrow (+H)$; (2) $N$ type, $0 \rightarrow (-H) \rightarrow 0 \rightarrow (+H) \rightarrow 0 \rightarrow (-H)$.

The first $0 \rightarrow (+H)/(-H)$ curve is called an initial magnetization curve. Generally, these two kinds of measurements will obtain the same loop except for the initial magnetization curve. Thus, only one of them has been used to obtain a $M(H)$ loop in the previous studies. However, they will give the different results in the present study.

Figure 1(a) shows the temperature dependence of magnetization [$M(T)$] of NiMnIn$_{13}$ ($T_N \sim 410$ K) measured under $H = 10$ Oe after ZFC and FC. The ZFC curve exhibits a peak at $T_p = 53$ K and an irreversibility between ZFC and FC curves occurring at $T_f \sim 150$ K, which is similar to that of NiCoMnSn [15]. The magnetic state of NiMnIn$_{13}$ at low temperatures is superparamagnetic (SPM) domains embedded in AFM matrix as in NiCoMnSn. The SPM domains are collectively frozen forming a superspin glass (SSG) state at lower temperatures [15]. The $M(H)$ curve at 300 K is a straight line without any SPM or FM feature, which indicates that the $T_c$ is at lower temperature [inset of Fig. 1(a)]. To further confirm this SSG state, we measured ac susceptibility at various frequencies ($f$s) with an ac magnetic field of 2.5 Oe after ZFC from 300 K. Figure 1(b) shows the temperature dependence of the real part of ac susceptibility. The $T_p$ increases with increasing frequency, which can be fitted to a critical power law for SSG [16].
FIG. 1 (color online). (a) $M(T)$ curves measured under $H = 10$ Oe after ZFC and FC. The inset shows the $M(H)$ curve at 300 K. (b) Temperature dependence of the real part of the ac susceptibility measured at frequencies $f = 0.1$, 1, 10, 100, and 1000 Hz with ac magnetic field of 2.5 Oe after ZFC from 300 K. The inset shows the plot of $\log_{10} M$ vs $\log_{10}(f/T_g - 1)$ (open circles) and the best fit to Eq. (1) (solid line). (c) and (d) $M(H)$ loops of NiMnIn13 at 10 K with $|H_{m}^\text{max}| = 40$ kOe after ZFC and FC ($H = 40$ kOe) from 300 K. The dashed lines show the initial magnetization curves. The insets show the larger scale at the low field.

$$\tau = 1/(2\pi f) = \tau^*(T_p/T_g - 1)^{-z\nu}$$ (1)

where $\tau^*$ is the relaxation time of individual particle moment, $T_g$ is the static glass temperature and $z\nu$ is the dynamic critical exponent. Our data can be fitted well by Eq. (1) with $\tau^* = 10^8$ s, $z\nu = 9.7$, and $T_g = 52$ K [inset of Fig. 1(b)]. These values are close to those reported for SSG ($\tau^* = 10^8$ s and $z\nu = 10.2$) [17]. Furthermore, the memory effect of SSG state has also been observed in NiMnIn13 [14].

The CEB effect after FC is observed in all NiMnIn$_x$ ($x = 11, 12, 13, 14, \text{ and } 15$) bulk alloys [14]. Here, we investigate the $M(H)$ loops at 10 K after ZFC from an unmagnetized state in these alloys. The unmagnetized initial state at 10 K in these alloys can be obtained easily if they are zero-field cooled from 300 K due to their $T_c$’s being lower than 300 K [14]. Figure 1(c) shows the $P$ type $M(H)$ of NiMnIn13 at 10 K after ZFC from 300 K with maximum measurement field $|H_{m}^\text{max}| = | + H | = | - H | = 40$ kOe. The dashed line shows the initial magnetization curve, which lies outside the major hysteresis loop. The magnetization at the starting point of the initial magnetization curve ($H = 0$) is zero, indicating that the initial state at 10 K is an unmagnetized state [14]. It is worth noting that the ZFC $M(H)$ loop shows a large shift along the magnetic field axis, which has never been observed in any previous CEB systems. The equal magnetization values in the highest positive and negative magnetic fields indicate the shifted loop is not a nonsymmetrical minor hysteresis loop [14]. We also measured the $N$ type $M(H)$ loops with opposite direction of the initial magnetization field at 10 K after ZFC [Fig. 1(d)] [14], which shift to the positive magnetic field axis showing a centrally symmetric image of the $P$ type $M(H)$ loops. This result cannot be expected from the effect of the remanent field of superconductor magnet or remanent magnetization of the samples, in which the shift direction of $M(H)$ loop is independent of the direction of the initial magnetization field. Furthermore, both the EB field ($H_{EB}$) and coercivity ($H_c$) after ZFC can be larger than those after FC [Fig. 1(c)] [14], which indicates that the EB after ZFC in the present case is not a spontaneous EB [10]. The $H_{EB}$ and $H_c$ are defined as $H_{EB} = -(H_L + H_R)/2$ and $H_c = -(H_L - H_R)/2$, respectively, where $H_L$ and $H_R$ are the left and right coercive fields. To further confirm this phenomenon after ZFC, we measured the temperature dependence of $H_{EB}$ and $H_c$ for $|H_{m}^\text{max}| = 40$ kOe and the training effect at 10 K for several selected $|H_{m}^\text{max}|$s [14], which are similar to those in the CEB systems obtained after FC [5,18]. The key difference is that EB in NiMnIn13 can be observed after ZFC from an unmagnetized state. Namely, FM unidirectional anisotropy, usually obtained by FC from higher temperature, can be induced isothermally during the initial magnetization process.

To investigate its origin, we consider the evolution of the initial magnetic state of NiMnIn13 after ZFC under external magnetic field as shown in Fig. 2. It is a simplified schematic diagram with SPM domains embedded in an AFM single domain (the AFM anisotropy axis is parallel to the direction of applied magnetic field). The applied magnetic field aligns all the SPM domains along the direction of external field. The Zeeman energy of
AFM spins (\(J_{ZE}\), which is proportional to the magnitude of magnetic field) near the interface is larger than the coupling energy of SPM-AFM at the interface \(J_{\text{int}}\), constant) and their anisotropy energy (constant), the applied field will align these AFM spins along the direction of external field [19]. Therefore, the SPM domains will grow in size. However, the enlarged SPM domains are at a metastable state and the coupling interface of SPM-AFM remains unchanged at this stage [see the dashed white circles in Fig. 2]. After removal of external magnetic field, they will shrink and return to their initial sizes due to the AFM anisotropy energy.

The growth of SPM domain size will decrease the interdomain distance; thus, the interaction between SPM domains increases. This is similar to the process of increasing the concentration of SPM nanoparticles in the conventional SSG systems [16]. When the interaction between SPM domains reaches the critical value, the coupling of SPM domains will become superferromagnetic (SFM) exchange through tunnelling superexchange [16]. The difference between SFM and conventional FM is that the atomic spins in the conventional FM are replaced by the superspins of SPM domains. The formation of SFM exchange may change the internal interaction of each enlarged SPM domain (metastable at SSG state) such that they become stable as shown in Fig. 2. [While in the case of SFM nanoparticles embedded in AFM matrix with a chemical interface (different materials) [6], the SPM nanoparticles cannot grow to form larger stable particles at the expense of AFM matrix]. As a result, a new stable SFM-AFM interface with unidirectional moment of SFM is formed and will pin the SFM superspins below the blocking temperature \((T_B)\), which is similar to an FM-AFM interface with unidirectional FM spins formed after FC in the CEB systems. The difference is that in the present case the SFM-AFM interface is induced isothermally by an external magnetic field. While in the CEB systems it is usually reconfigured under FC. According to this model, the moment of SPM domains increases with increasing size under external magnetic field. We have only considered AFM domains with anisotropy axis parallel to external magnetic field in this model. For AFM domains with anisotropy axis nonparallel to external magnetic field, there is an angle between the direction of the initial magnetization field and the anisotropy axis. This configuration can still result in EB effect, which is similar to the EB effect in the CEB systems with different angles between the direction of the cooling field and the AFM anisotropy axis [20]. Based on the above analyses, we believe that a SFM unidirectional anisotropy, which is similar to an FM unidirectional anisotropy, can be formed during the initial magnetization process.

In order to confirm this model, we further measured the \(M(H)\) loops with various magnitudes of the initial magnetization fields (different \(H_{m}^{\text{max}}\))s at 10 K after ZFC from 300 K [14]. Figure 3(a) shows \(H_{EB}\) and \(H_{c}\) as a function of \(H_{m}^{\text{max}}\). There is a critical \(H_{m}^{\text{max}}\) \((H_{\text{EB}}^{\text{crit}}) = 30\text{ Koe}\), at which \(H_{EB}\) reaches the maximum value and \(H_{R}\) remains almost constant at higher \(H_{m}^{\text{max}}\) [Fig. 3]. The maximum \(H_{EB}\) means the formation of the maximum FM unidirectional anisotropy [5]. Thus, the meaning of \(H_{EB}^{\text{crit}}\) is that at which the SSG state completely transforms to SFM state, producing maximum SFM unidirectional anisotropy. The decrease of the \(H_{EB}\) at higher \(H_{m}^{\text{max}}\) is only due to the decrease of the \(H_{L}\) [Fig. 3(b)], which may originate from the change of bulk AFM spin structure under large applied magnetic field [14]. The bulk AFM spin structure has been shown to play a crucial role in EB effect in thin film system [21].

When \(H_{m}^{\text{max}} < H_{EB}^{\text{crit}}\), only part of the SSG state transforms to the SFM state during the initial magnetization process. For the SSG state, there is a remanent magnetization and \(H_{R}\) in \(M(H)\) loops due to irreversible switching of a collective state [17]. The \(H_{R}\) (both \(H_{L}\) and \(H_{R}\)) increases with increasing \(H_{m}^{\text{max}}\) (a series of minor hysteresis loops). However, the number of SPM domains at SSG state will decrease with increasing \(H_{m}^{\text{max}}\) due to more SSG state transforming to SFM state, which generates more new interfaces with SFM unidirectional anisotropy. Thus, the \(H_{EB}\) increases with increasing \(H_{m}^{\text{max}}\) at this stage, leading to the increase of coercive field in one direction \((H_{L})\) and the decrease in the other \((H_{R})\). The final coercive fields are attributed to a combined effect of SPM domains in SSG and SFM states. Because of the opposite \(H_{m}^{\text{max}}\) dependence for these two effects, the \(H_{R}\) reaches maximum at a field smaller than \(H_{EB}^{\text{crit}}\). For \(H_{L}\), both effects have the same \(H_{m}^{\text{max}}\) dependences, resulting in a continuous increase of \(H_{L}\) with \(H_{m}^{\text{max}}\). As a result, the field, at which \(H_{c}\) reaches maximum, is smaller than the \(H_{EB}^{\text{crit}}\) of \(H_{EB}\). Further supports to the model shown in Fig. 2 are provided in the supplementary information including anomalous remanent magnetization dependence of EB effect, isothermal tuning of EB after ZFC from an unmagnetized state, and strong cooling field dependence of CEB effect in NiMnIn13 [14].

Finally, we have further verified the model by changing the size of the initial domains, which is crucial to the formation of the SFM unidirectional anisotropy [14]. If
which is consistent with the previous results [22]. The SPM domain makes the than that of NiMnIn13 at the initial state. The larger size of \(x/C24\) Ni\(_{50}\)Mn\(_{25}\)In\(_{25}\) compared with that of the stoichiometric compound Ni\(_{50}\)Mn\(_{50}\)In\(_{10}\) results in the formation of FM domains at a larger volume fraction, resulting in the SFM domains no longer separate from each other in the SFM volume fraction increases from \(x=11, 12\), and 14, 15 (left).

For the size of the initial domains is larger than the critical value, SFM or FM domains will form and no EB effect will appear after ZFC [13]. Figure 4(a) shows the \(M(H)\) curves of NiMnIn\(_{13}\) at 10 K. The saturation magnetization of NiMnIn\(_x\) increases with increasing In content [Fig. 4(b)], which is consistent with the previous results [22]. The \(T_c\)'s of these alloys are lower than 300 K and the \(T_c\)'s decreases continuously with increasing In content [14]. The saturation magnetization of NiMnIn\(_x\) at 10 K is very small compared with that of the stoichiometric compound Ni\(_{50}\)Mn\(_{25}\)In\(_{25}\) (80 emu/g, pure FM state at low temperatures) [22]. The increase of saturation magnetization in the off-stoichiometric alloys is due to the excess of Mn atoms occupying a number of In sites, which produces AFM coupling [22]. The SFM (may include some SPM or FM domains) volume fraction increases from \(\sim 1\%\) in NiMnIn\(_{11}\) to \(\sim 35\%\) in NiMnIn\(_{15}\) at 10 K [Fig. 4(b)]. Thus, the average domain size in \(x=14\) alloy is larger than that of NiMnIn\(_{13}\) at the initial state. The larger size of SPM domain makes the \(H^{\text{crit}}= 15\) kOe, at which all of the SSG states transforms to SFM state, being smaller than that of NiMnIn\(_{13}\) [Fig. 4(c)]. Furthermore, the SFM volume fraction in \(x=14\) is about 22\% (the total volume fraction of SFM and SPM in the initial state is less than this value), which is close to the threshold concentration for percolation in three dimensional system (\(\sim 16\%)\) [23]. The SFM domains no longer separate from other in the AFM matrix at a larger volume fraction, resulting in the formation of FM domains at \(x>14\). For \(x=15\) alloy, there is no SFM domains at the initial state and the \(M(H)\) loops after ZFC shows double-shifted behavior with no EB effect, which is similar to the results of NiMnIn\(_{16}\) [13,14]. For \(x=11\) and 12, the continuous increase of \(H_{EB}\) with \(H^{\text{max}}\) up to 80 kOe is due to the smaller size of SPM domain, which is similar to results of NiMnIn\(_{13}\) for \(H^{\text{max}} < H^{\text{crit}}\). Large \(H_c\) has also been observed for \(x=11\) and 12 and the \(H_c\) of NiMnIn\(_{12}\) shows tendency to maximum value at higher \(H^{\text{max}}\)'s prior to the maximum of \(H_{EB}\) [Fig. 4(d)]. All of these results are consistent with the discussions in NiMnIn\(_{13}\) within the model as shown in Fig. 2.

In summary, we have observed a large EB effect after ZFC from an unmagnetized state in Ni-Mn-In bulk alloys, exhibiting the same relationship of the temperature dependence of \(H_{EB}\) and \(H_c\), and the training effect as in the CEB systems after FC. Such phenomenon is attributed to a SFM unidirectional anisotropy formed during the initial magnetization process. These results will open a new direction to realize EB effect.

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